

170- μ Vrms ZERO-RIPPLE SWITCHED CAP BUCK-BOOST CONVERTER FOR VCO SUPPLY

FEATURES

- **Wide Input Voltage Range:**
 - 1.8 V To 5.5 V for 2.7-V, 3-V, 3.3-V Output (TPS60240/2/3)
 - 2.7 V To 5.5 V for 5-V Output (TPS60241)
- **170- μ Vrms Zero Ripple Output:**
 - at 20 Hz to 10 MHz Bandwidth
- **Minimum Number of External Components**
 - No Inductors
 - Only Small Ceramic Chip Capacitors
- **Up to 90% Efficiency**
- **Regulated 3.3-V (TPS60240), 5-V (TPS60241), 3-V (TPS60243), and 2.7-V (TPS60242) Output Voltage With $\pm 2.5\%$ Accuracy Over Load**
- **Up to 25-mA Output Current**
- **Shutdown Mode: 0.1 μ A Typical**
- **Thermal Protection and Current Limit**
- **Microsmall 8-Pin MSOP Package**
- **EVM Available TPS60241EVM-194**

- **Digital Cameras**
- **MP3 Players**
- **SIM Modules**
- **Electronic Games**
- **Memory Backup**
- **Handheld Meters**
- **Bias Supplies**

DESCRIPTION

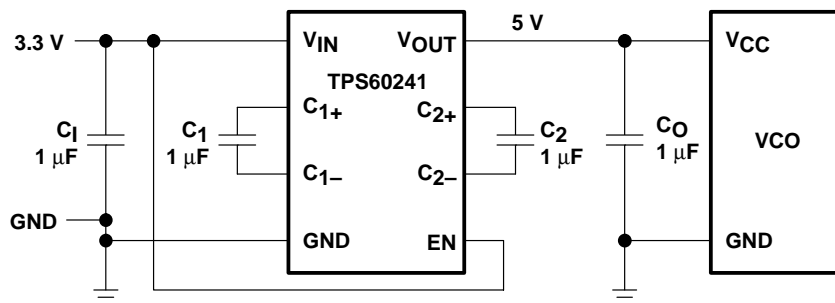
The TPS6024x is a switched capacitor voltage converter, ideally suited for VCO and PLL applications that require low noise and tight tolerances. Its dual-cap design uses four ceramic capacitors to provide ultralow output ripple yet high efficiency, while eliminating the need for inefficient linear regulators.

A wide input supply voltage range of 2.7 V to 5.5 V makes the TPS6024x ideal for lithium-based battery applications. The TPS60240/2/3 operates down to 1.8 V, supporting a 3.3-V, 2.7-V, 3-V output from two-cell, nickel- or alkaline-based chemistries. The devices work equally well for low EMI dc/dc step-up conversion without the need for an inductor. The high switching frequency (typical 160 kHz) promotes the use of small surface-mount capacitors, saving board space. The converter's shutdown mode conserves battery energy.

APPLICATIONS

- **VCO and PLL Power for:**
 - PDA Phones
 - Cellular Phones
 - PCMCIA Modems
- **Smartcard Readers**

typical application circuit



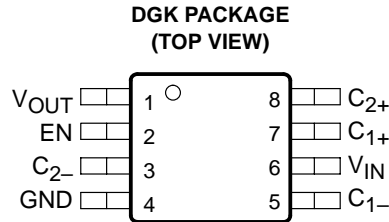
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TPS60240, TPS60241 TPS60242, TPS60243

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description(continued)

The devices are thermally protected and current-limited for reliable operation even under persisting fault conditions. Normal quiescent current (ground pin current) is only 250 μ A, and typically 0.1 μ A in shutdown mode. The TPS6024x devices come in a thin, 8-pin MSOP (DGK) package with a component height of only 1,1 mm.

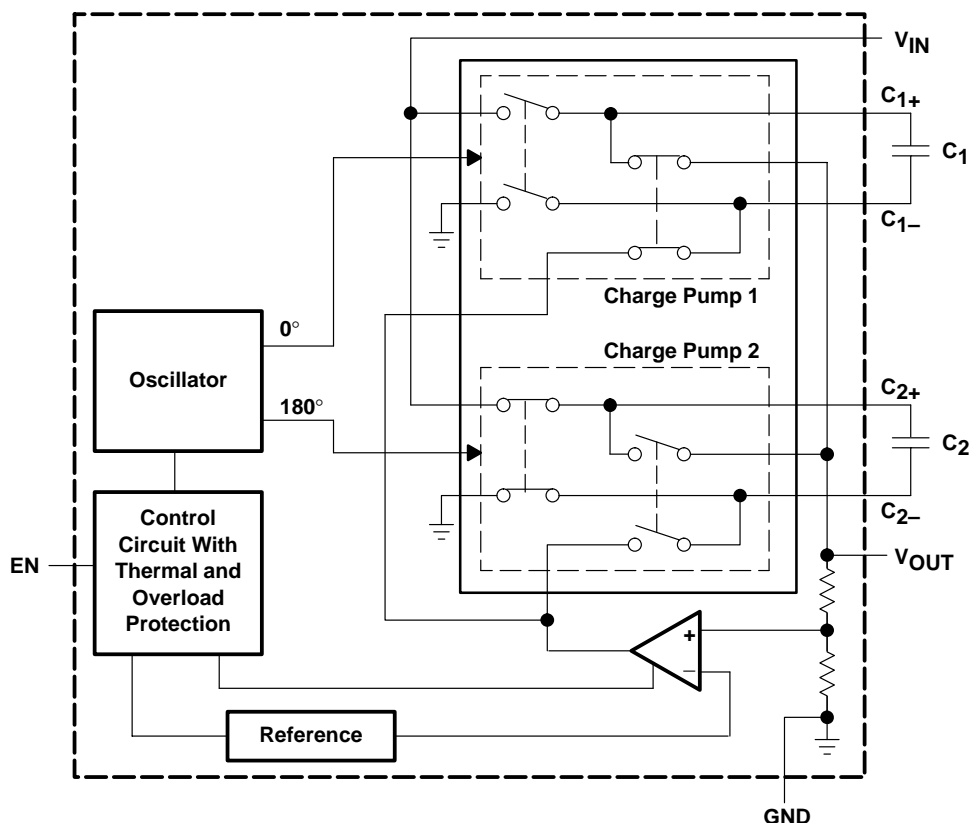


AVAILABLE OPTIONS

T _A	PART NUMBER†	PACKAGE MARKING	PACKAGE	OUTPUT VOLTAGE (V)
–40°C to 85°C	TPS60241DGKR	AUB	DGK (8-pin MSOP)	5 V
–40°C to 85°C	TPS60240DGKR	ATM	DGK (8-pin MSOP)	3.3 V
	TPS60242DGKR	AYF	DGK (8-pin MSOP)	2.7 V
	TPS60243DGKR	AYG	DGK (8-pin MSOP)	3 V

† This package type is available taped and reeled only. Quantity is 2500 units per reel (e.g., TPS60241DGKR). The devices are also available on mini reel with 250 units per reel. To order this packaging option, replace the R with a T in the part number (e.g., TPS60261DGKT).

functional block diagram



Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
C1+	7		Positive terminal of the flying capacitor C ₁
C1-	5		Negative terminal of the flying capacitor C ₁
C2+	8		Positive terminal of the flying capacitor C ₂
C2-	3		Negative terminal of the flying capacitor C ₂
EN	2	I	Enable terminal, active high
GND	4		Ground
V _{IN}	6	I	Supply voltage input TPS60241: 2.7 V to 5.5 V, TPS60240/2/3: 1.8 V to 5.5 V. Bypass V _{IN} to GND with a 1-μF external capacitor (C _I).
V _{OUT}	1	O	Regulated power output. Bypass V _{OUT} to GND with a 1-μF external filter capacitor (C _O). TPS60241: regulated 5-V output, TPS60240: regulated 3.3-V output, TPS60242: regulated 2.7-V output, TPS60243: regulated 3-V output

detailed description

operating principle

The TPS6024x charge pump is a fixed-frequency, dual-phase charge pump that provides 25 mA of continuous supply current for low-noise applications such as VCOs used in cell phones and wireless appliances.

Low-noise operation results from using a proprietary dual-phase charge pump topology that relies on an operational amplifier in the feedback loop to reduce ripple. During the first phase, C₁ is charged to the supply voltage. Terminal C₁₊ is connected to V_{IN}, and C₁₋ is connected to GND. In the second phase, C₁₋ is connected to the output of the operational amplifier, and C₁₊ is connected to V_{OUT}. The operational amplifier then adjusts its output until the output V_{OUT} delivers the correct voltage to make the resistor divided feedback point equal to the reference voltage. During this second phase, C₂ is charged to supply voltage. Terminal C₂₋ is connected to GND, and C₂₊ is connected to V_{IN}. Phase one is then repeated with C₂, now acting to provide charge to the output in place of C₁, which is connected to the supply. The dual-phase operation lowers the output ripple voltage significantly compared to a standard single-phase charge pump. In addition, the linear feedback of the operational amplifier eliminates the ripple during discharge of the output capacitor (C_O).

shutdown

Driving EN low disables the converter. This disables the internal circuits and reduces input current to typically 0.1 μA. In this mode, the load is disconnected from the supply voltage. The device exits shutdown once EN is set to a high level.

start-up procedure

The converter is enabled when EN is set from logic low to high. The start-up time to reach 90% of the nominal output voltage is typically 0.5 ms at load currents lower than 10 mA and with an output capacitor of 1 μF. Increasing the values of C_O delays the start-up time.

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, V _{DD}	-0.3 V to 6 V
Power dissipation, P _D	Internally limited
Voltage EN	-0.3 V to 6 V
Voltage C ₂₋ , C ₁₋	-0.3 V to V _I or 5.5 V, whichever is lowest
Voltage C ₂₊ , C ₁₊	-0.3 V to V _I , V _O , or 5.5 V, whichever is lowest
Junction temperature, T _J	125°C
Storage temperature, T _{stg}	-65°C to 150°C
Shortcircuit output current	80 mA maximum

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
DGK	376 mW	3.76 mW/°C	207 mW	150 mW

NOTE: The thermal resistance junction to ambient of the DGK package is R_{TH-JA} = 150°C/W.

recommended operating conditions

		MIN	NOM	MAX	UNIT	
V _I	Input voltage range	TPS60240, TPS60242, TPS60243		1.8	5.5	V
		TPS60241		2.7	5.5	
I _O	Output current range	All devices			25	mA
C _I	Input capacitor				1	μF
C ₁ , C ₂	Flying capacitors				1	μF
C _O	Output capacitor				1	μF
T _A	Operating temperature range	-40		85	°C	

electrical characteristics for TPS6024X at T_A = 25°C, C_I = C_O = 1 μF, C₁ = C₂ = 1 μF (unless otherwise noted), limits apply over the specified temperature range, -40°C to 85°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
V _I	Input voltage	TPS60240 Assured start-up		I _O ≤ 5 mA, R _L = 600 Ω		1.8	5.5	V
		TPS60241 Assured start-up		I _O ≤ 12 mA, R _L = 417 Ω		2.7	5.5	
		TPS60242 Assured start-up		I _O ≤ 12 mA, R _L = 225 Ω		1.8	5.5	
		TPS60243 Assured start-up		I _O ≤ 10 mA, R _L = 300 Ω		1.8	5.5	
V _O	Output voltage	TPS60240		1.8 V ≤ V _I ≤ 5.5 V, 0 mA ≤ I _O ≤ 5 mA		3.2175	3.3	3.3825
				2.4 V ≤ V _I ≤ 5.5 V, 0 mA ≤ I _O ≤ 25 mA				
		TPS60241		2.7 V ≤ V _I ≤ 5.5 V, 0 mA ≤ I _O ≤ 12 mA		4.875	5	5.125
				3 V ≤ V _I ≤ 5.5 V, 0 mA ≤ I _O ≤ 25 mA				
		TPS60242		1.8 V ≤ V _I ≤ 5.5 V, 0 mA ≤ I _O ≤ 12 mA		2.6325	2.7	2.7675
				2.3 V ≤ V _I ≤ 5.5 V, 0 mA ≤ I _O ≤ 25 mA				
		TPS60243		1.8 V ≤ V _I ≤ 5.5 V, 0 mA ≤ I _O ≤ 10 mA		2.925	3	3.075
				2.3 V ≤ V _I ≤ 5.5 V, 0 mA ≤ I _O ≤ 25 mA				
I _O	Output current	TPS60240/2/3	Nominal	2 V ≤ V _I ≤ 5.5 V		12		
			Short circuit	V _I = 2 V		80		
		TPS60241	Nominal	2.7 V ≤ V _I ≤ 5.5 V		12		
			Short circuit	V _I = 3.25 V		80		
f _{OSC}	Internal clock source		100	160	220	kHz		
V _n	Output noise voltage	TPS60240/2/3		V _I < 2.5 V, I _O = 5 mA, ESR < 0.1 Ω, measured over 20 Hz to 10 MHz, C _O = 4.7 μF		170		
		TPS60241		V _I = 2.7 V, I _O = 5 mA, ESR < 0.1 Ω, measured over 20 Hz to 10 MHz, C _O = 4.7 μF		170		
V _{I(H)}	EN	Logic high input voltage V _{OH}		1.3		5.5	V	
V _{I(L)}	EN	Logic low input voltage V _{OL}		-0.2		0.4	V	
I _{I(H)}	EN	Logic high input current				100	nA	
I _{I(L)}	EN	Logic low input current				100	nA	
t _(EN)	EN	Start-up time		V _O > 90% of V _(NOM) 0.1 mA ≤ I _O ≤ 10 mA, C _O = 1 μF		0.5		
η	Efficiency	TPS60240		I _O = 5 mA, V _I = 1.8 V		89.6%		
		TPS60241		I _O = 10 mA, V _I = 2.7 V		90.8%		
		TPS60242		I _O = 10 mA, V _I = 1.8 V		73%		
		TPS60243		I _O = 10 mA, V _I = 1.8 V		81%		

**TPS60240, TPS60241
TPS60242, TPS60243**

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electrical characteristics for TPS6024X at $T_A = 25^\circ\text{C}$, $C_1 = C_O = 1\ \mu\text{F}$, $C_1 = C_2 = 1\ \mu\text{F}$ (unless otherwise noted), limits apply over the specified temperature range, -40°C to 85°C (continued)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_Q	Quiescent current	$I_O = 0\ \text{mA}$, $V_I = 3\ \text{V}$		250	325	μA
		In shutdown mode		0.1	1	
Thermal shutdown	Temperature activated			160		$^\circ\text{C}$
	Temperature deactivated			140		

TYPICAL CHARACTERISTICS

Table of Graphs

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Load transient response		26
Start-up timing		27
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Noise voltage spectrum		29
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TYPICAL CHARACTERISTICS

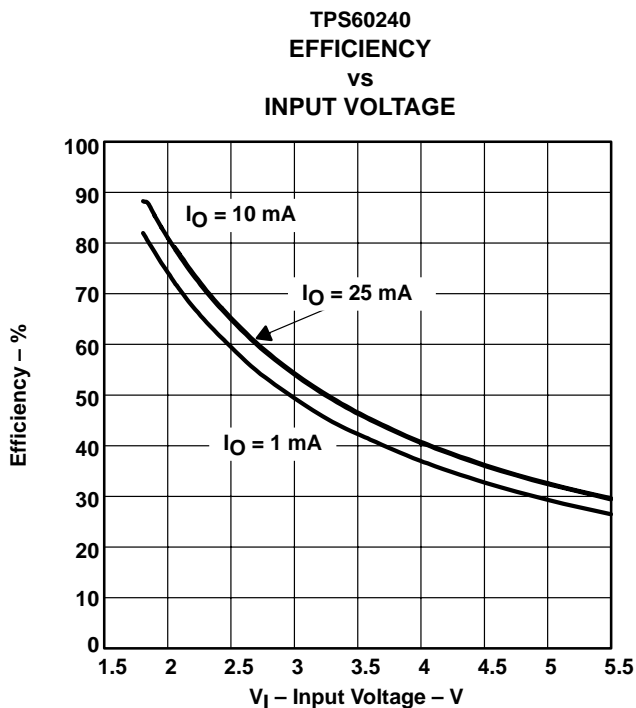


Figure 1

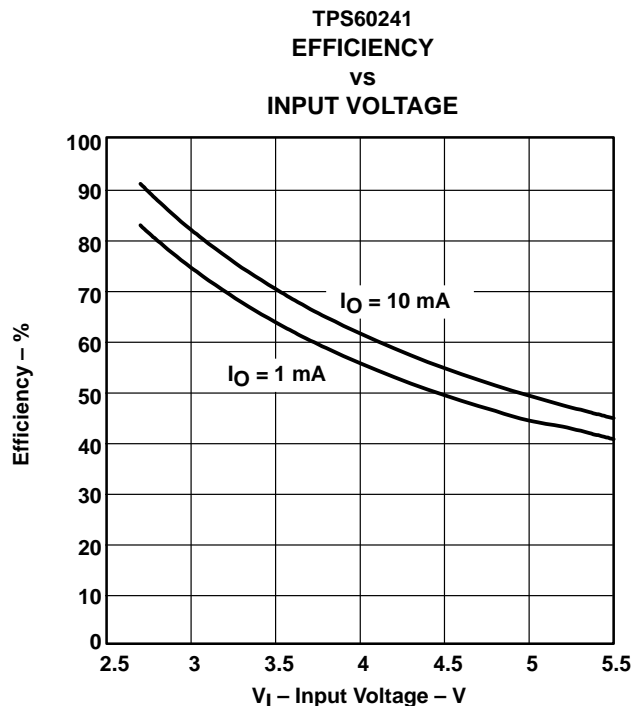


Figure 2

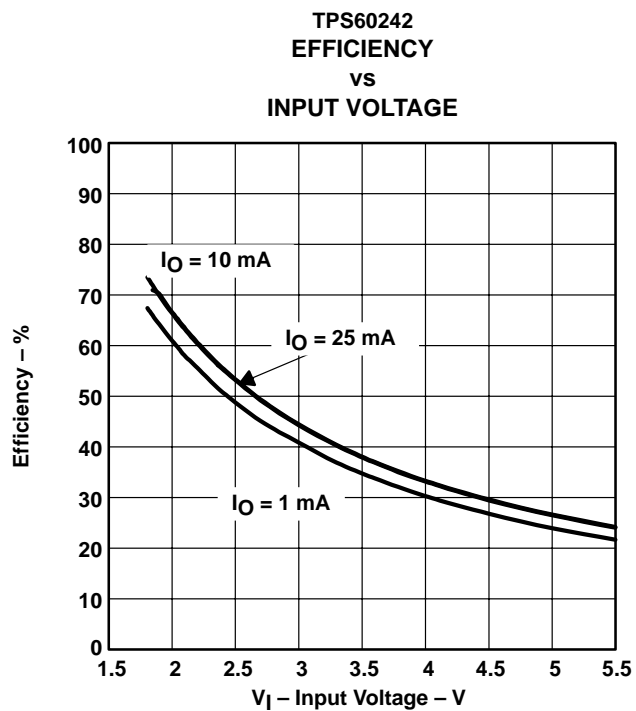


Figure 3

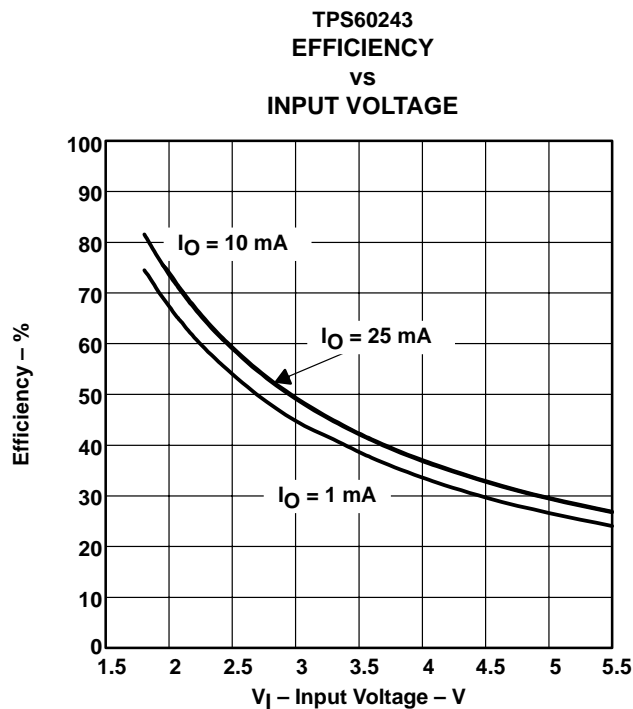


Figure 4

TYPICAL CHARACTERISTICS

TPS60240
 EFFICIENCY
 VS
 OUTPUT CURRENT

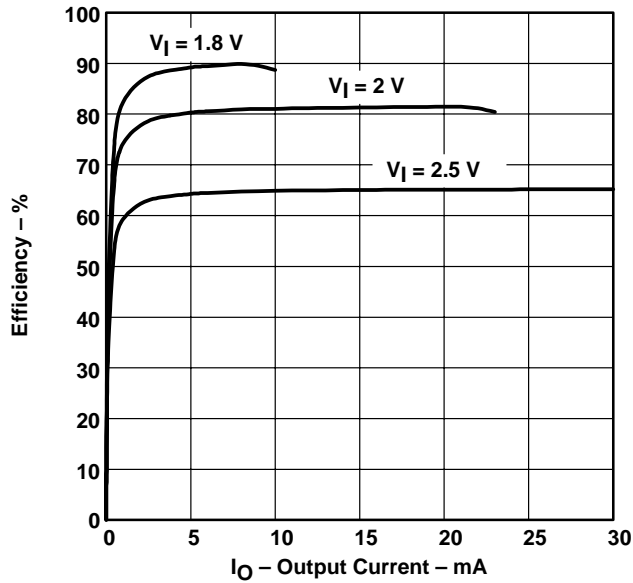


Figure 5

TPS60241
 EFFICIENCY
 VS
 OUTPUT CURRENT

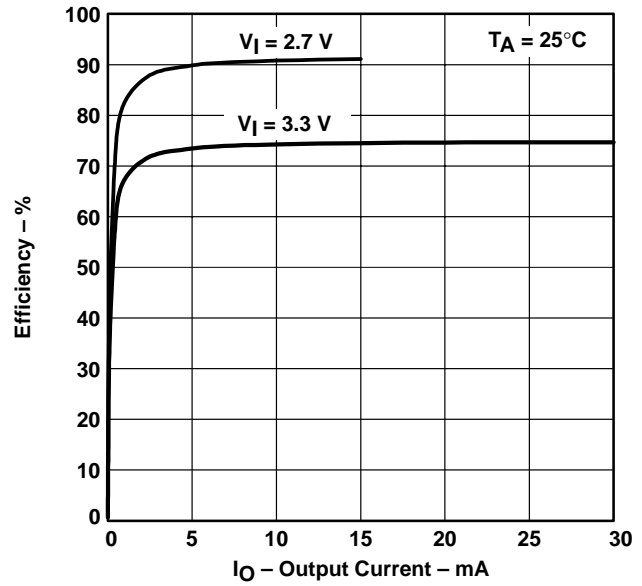


Figure 6

TPS60242
 EFFICIENCY
 VS
 OUTPUT CURRENT

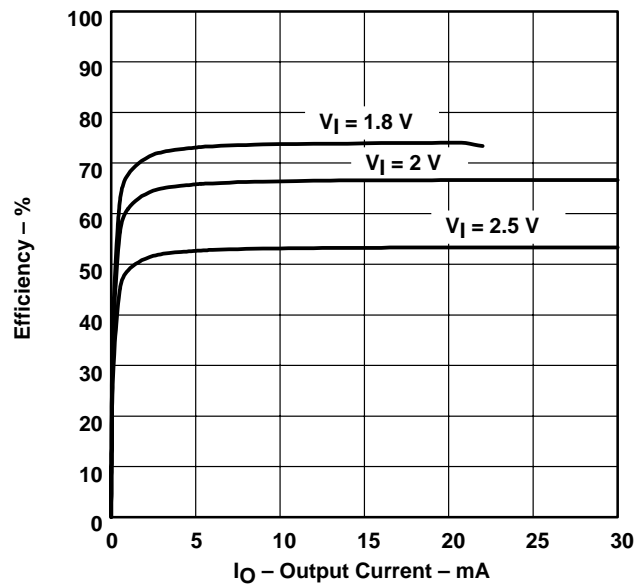


Figure 7

TPS60243
 EFFICIENCY
 VS
 OUTPUT CURRENT

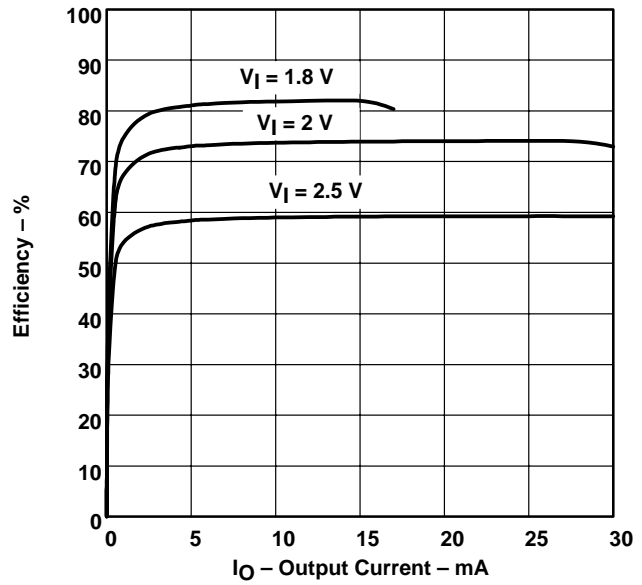


Figure 8

TYPICAL CHARACTERISTICS

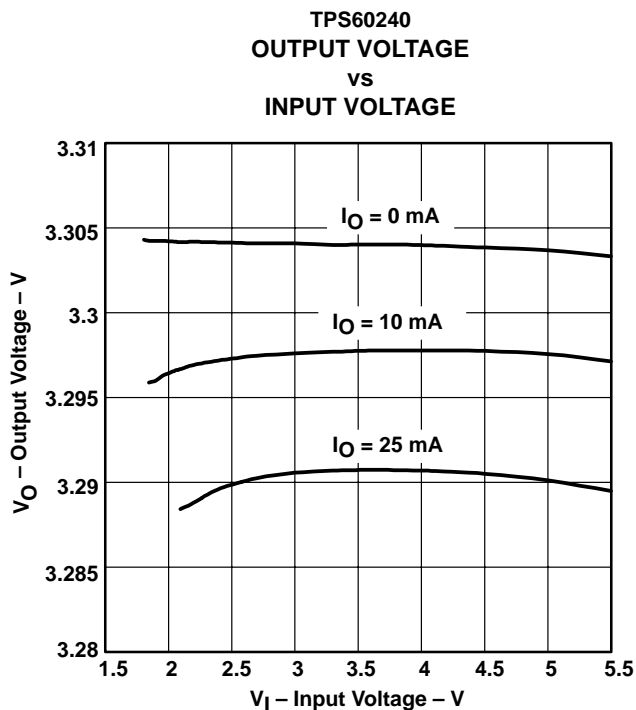


Figure 9

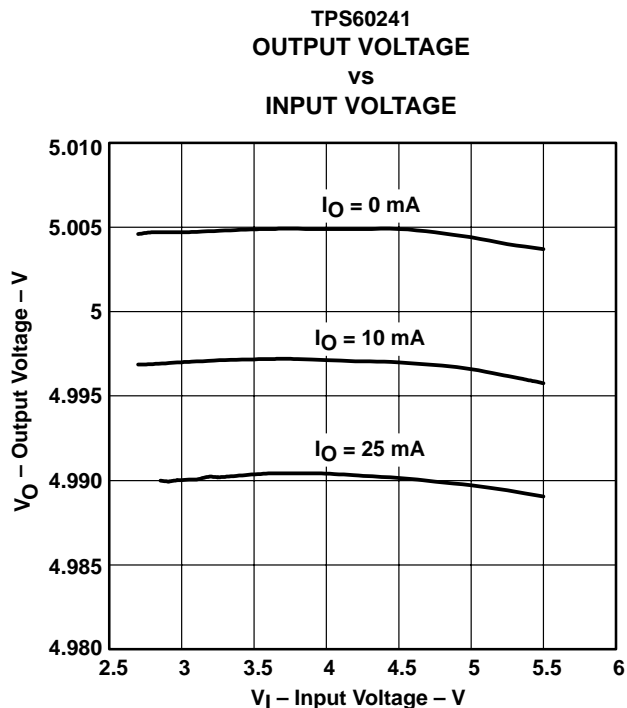


Figure 10

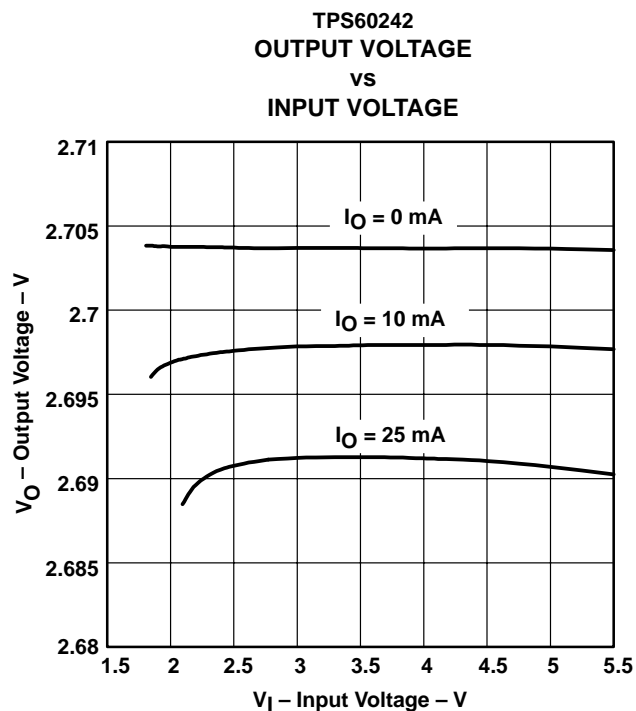


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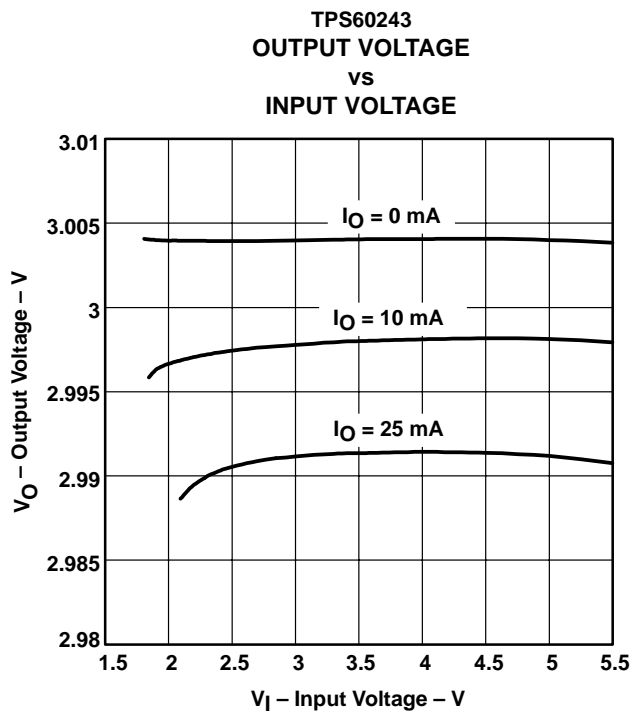


Figure 12

TYPICAL CHARACTERISTICS

TPS60240
 OUTPUT VOLTAGE
 VS
 OUTPUT CURRENT

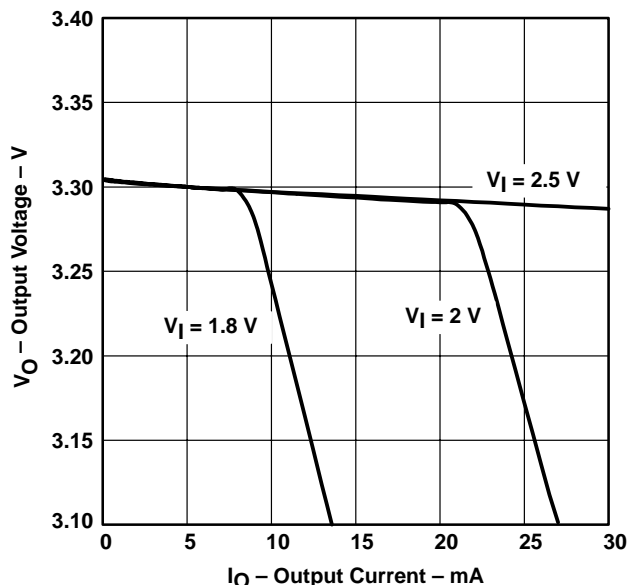


Figure 13

TPS60241
 OUTPUT VOLTAGE
 VS
 OUTPUT CURRENT

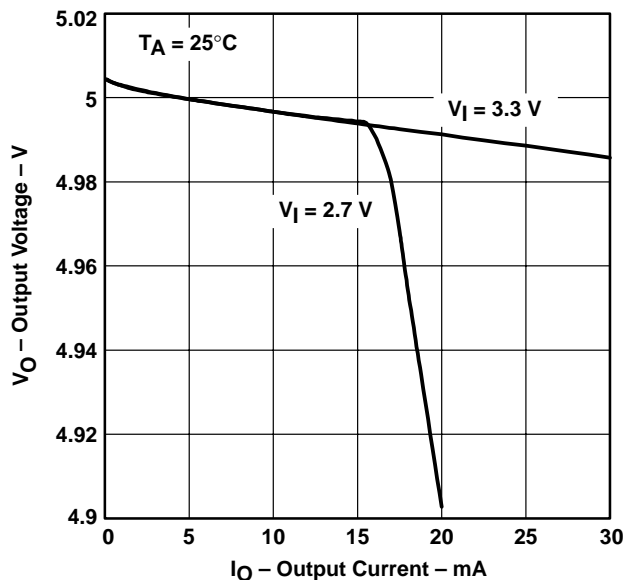


Figure 14

TPS60242
 OUTPUT VOLTAGE
 VS
 OUTPUT CURRENT

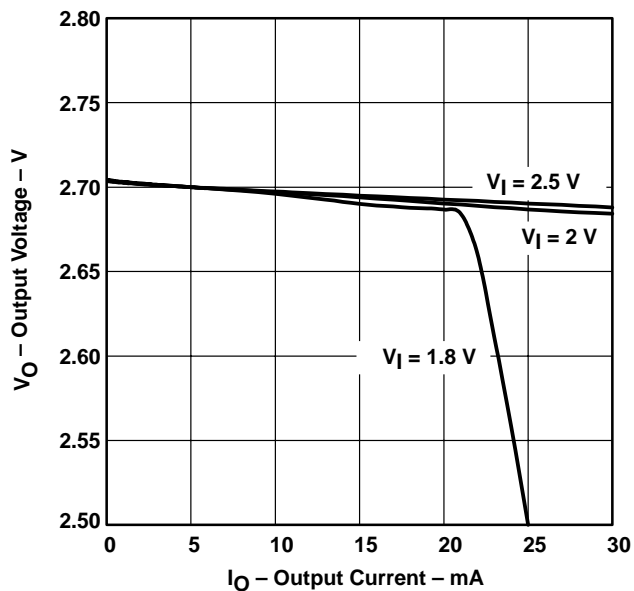


Figure 15

TPS60243
 OUTPUT VOLTAGE
 VS
 OUTPUT CURRENT

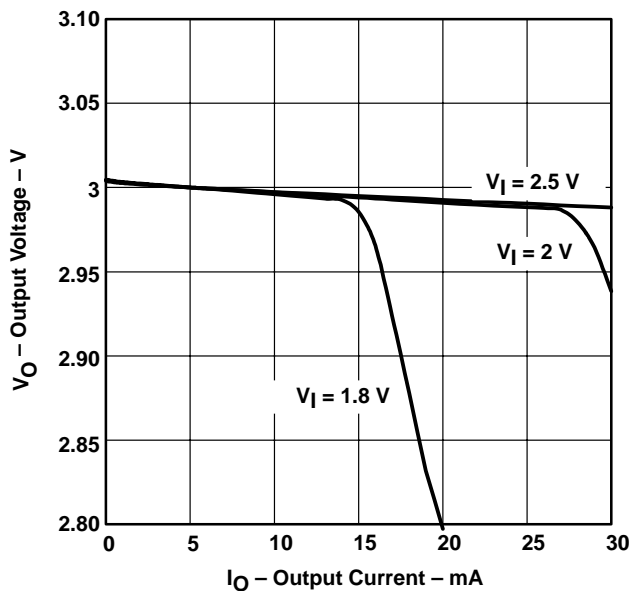


Figure 16

TYPICAL CHARACTERISTICS

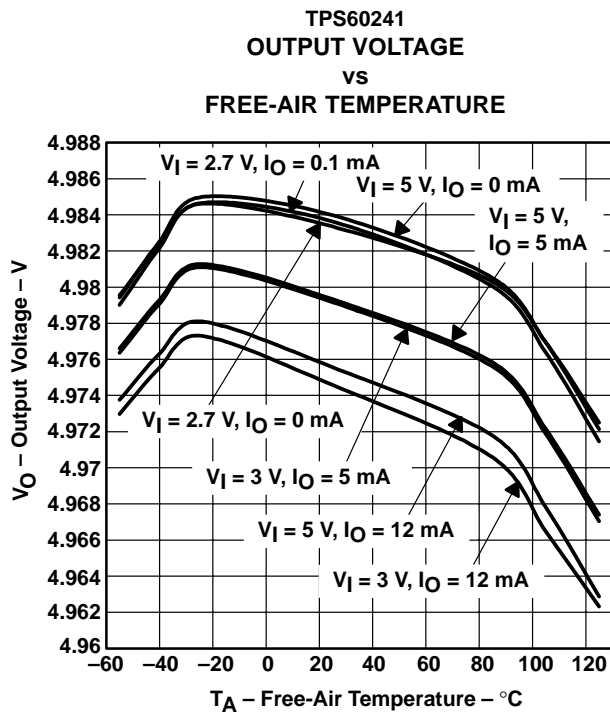


Figure 17

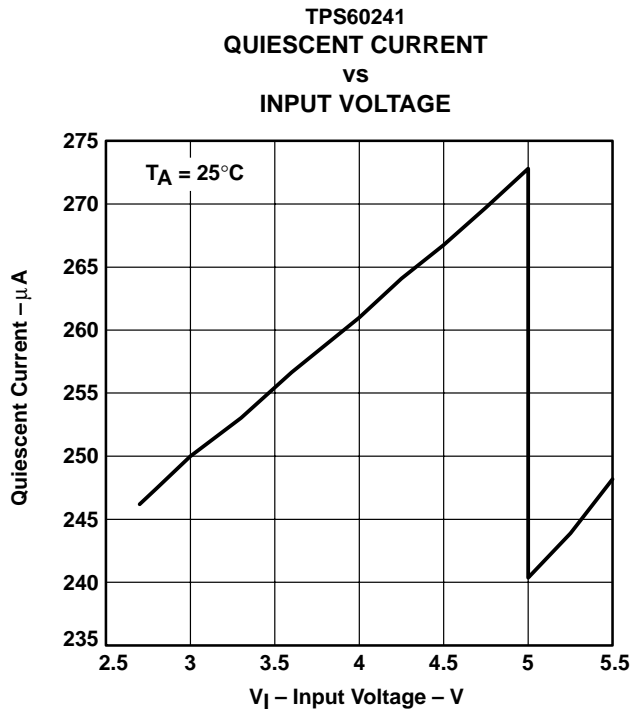


Figure 18

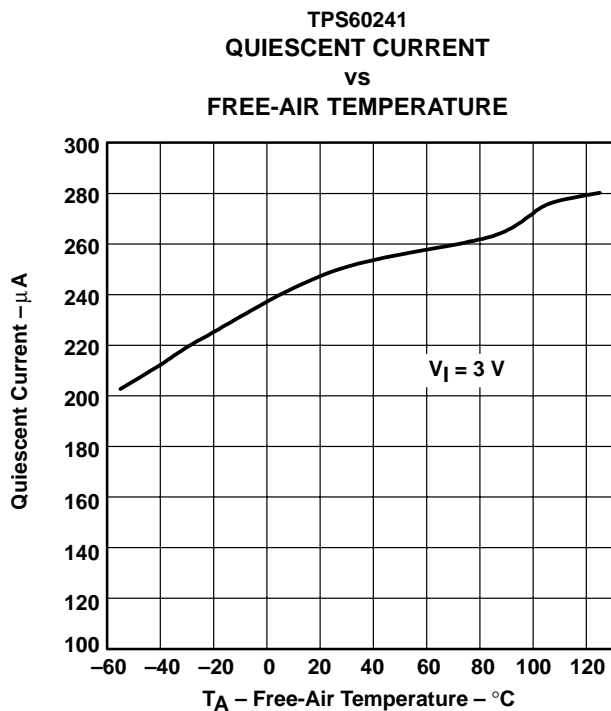


Figure 19

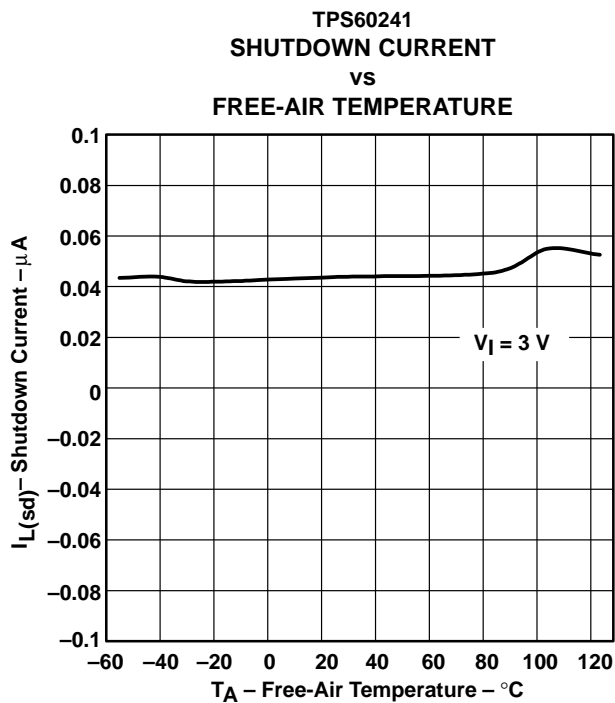


Figure 20

TYPICAL CHARACTERISTICS

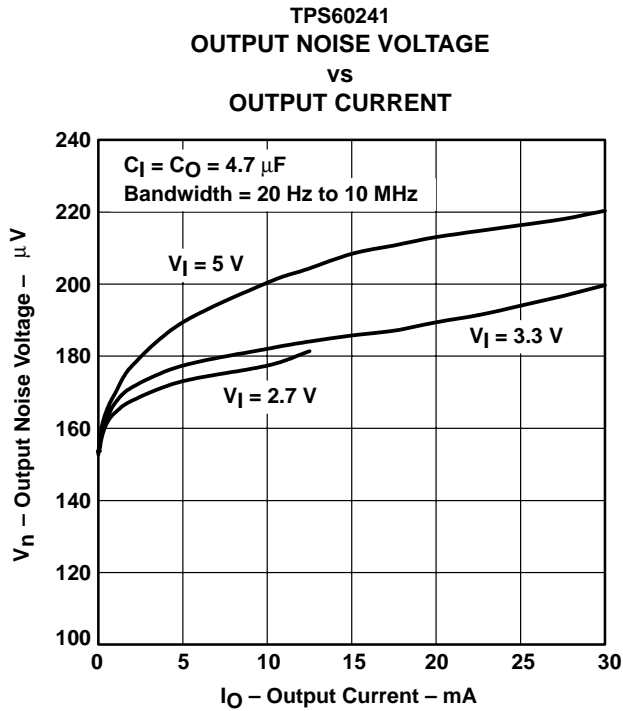


Figure 21

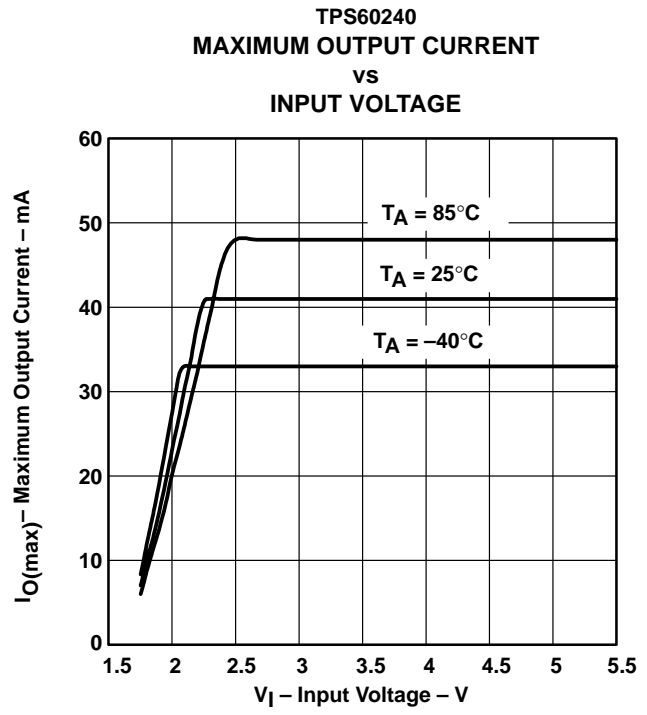


Figure 22

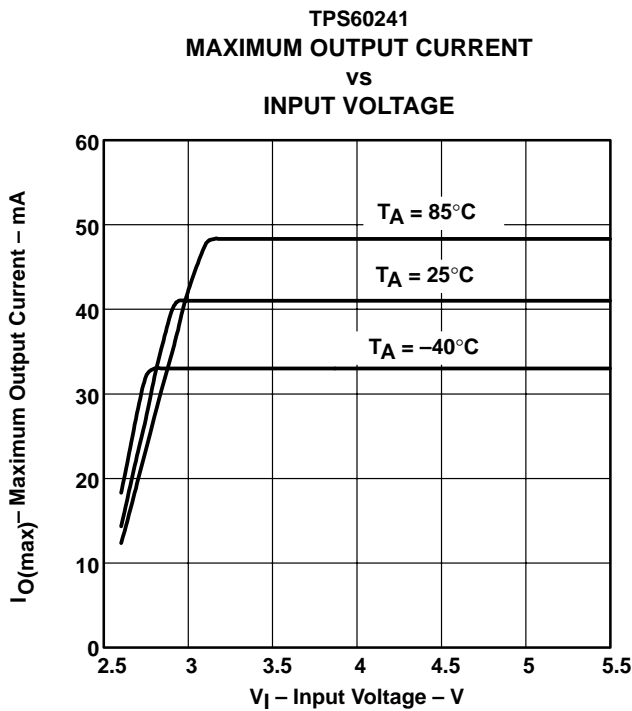


Figure 23

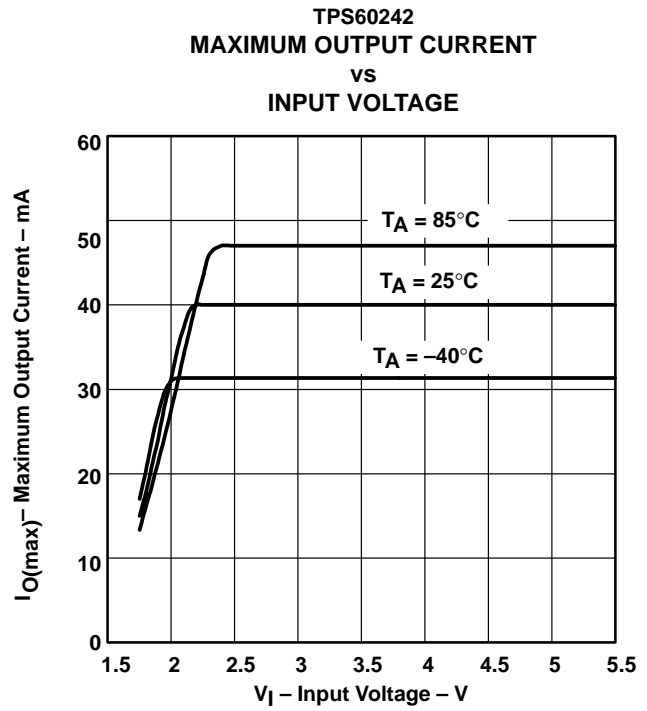


Figure 24

TYPICAL CHARACTERISTICS

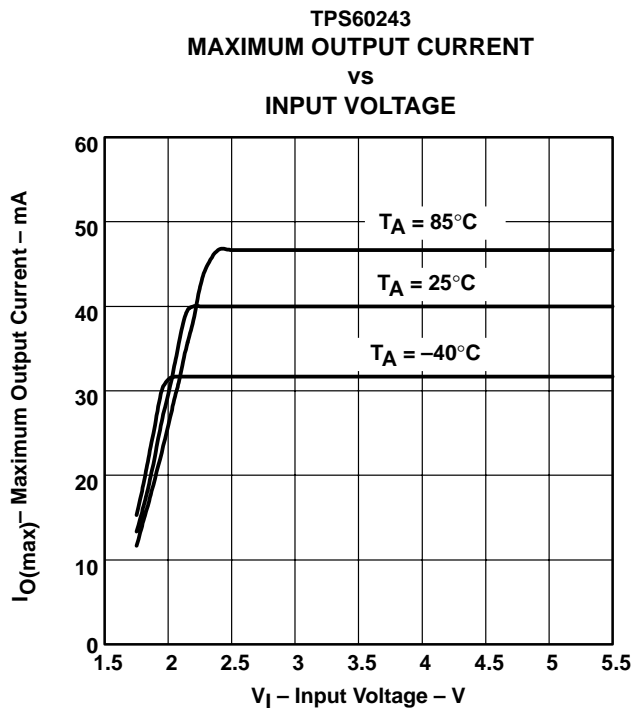


Figure 25

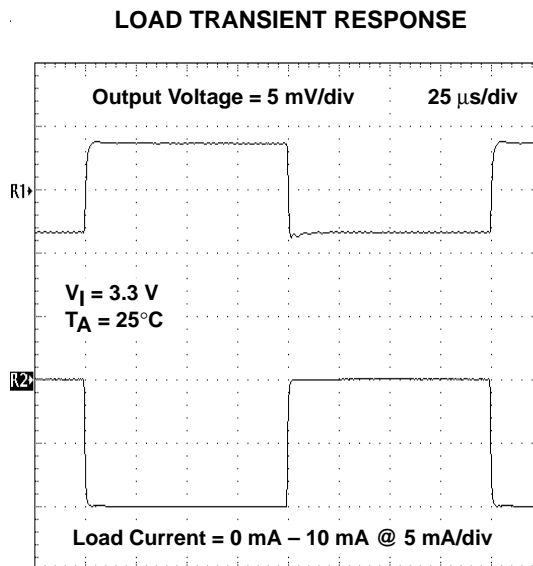


Figure 26

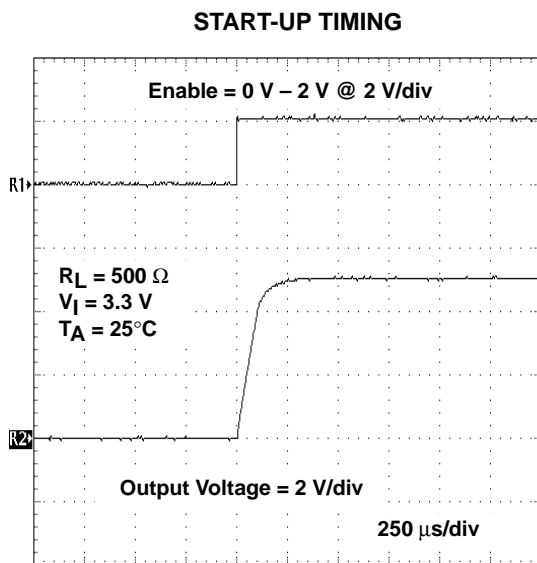


Figure 27

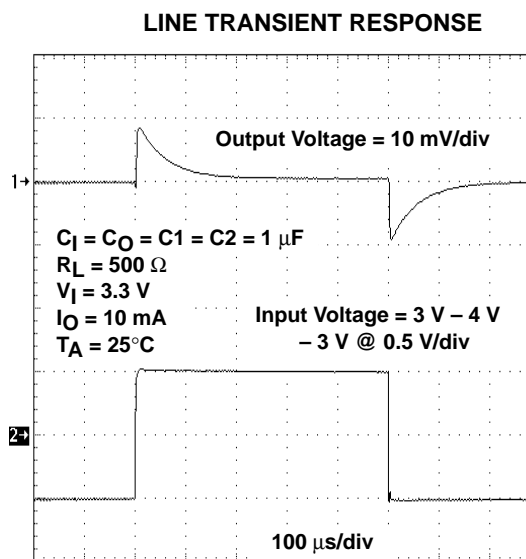
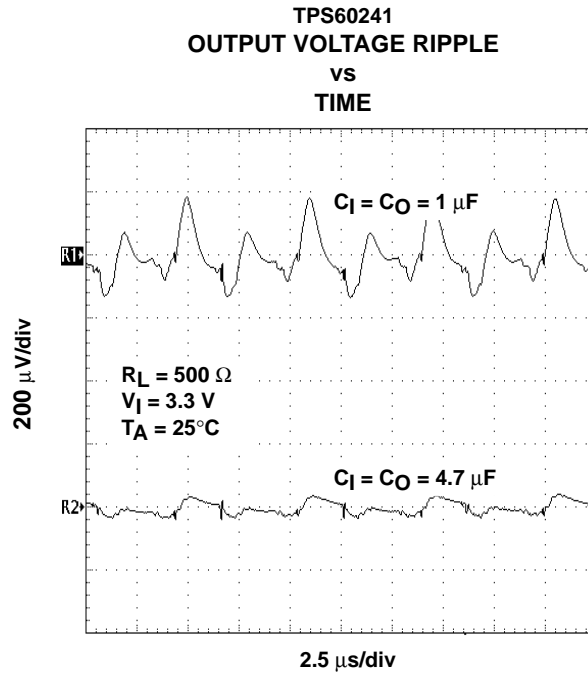
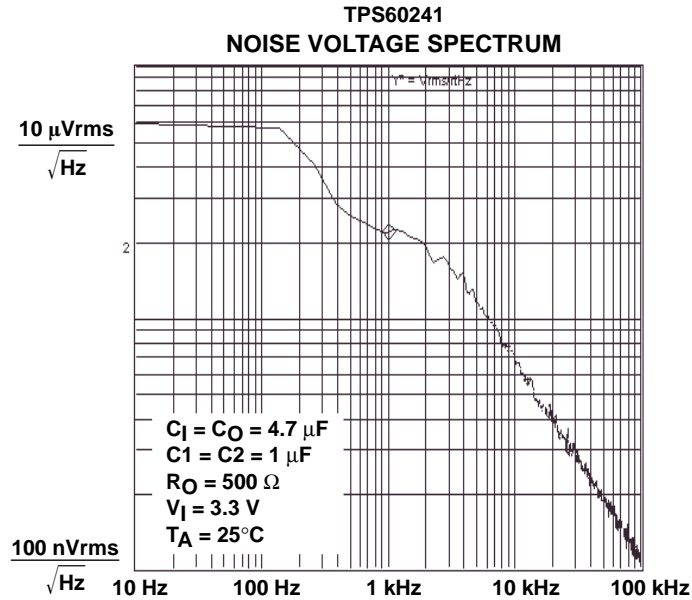


Figure 28

TYPICAL CHARACTERISTICS



NOTE: Scope triggered by voltage at flying capacitors, noise removed by averaging function and bandwidth limit 20 MHz.

APPLICATION INFORMATION

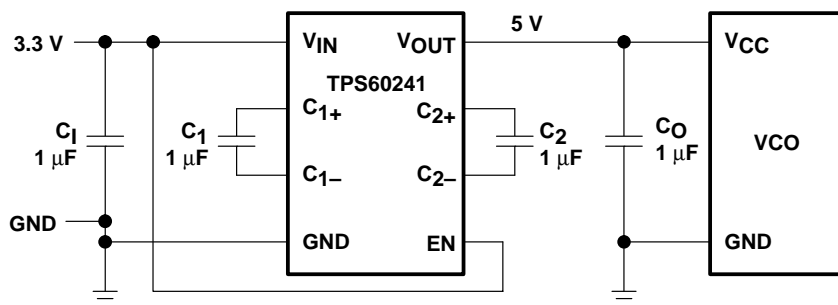


Figure 31. 5-V Low-Noise VCO Supply From 3.3-V Input

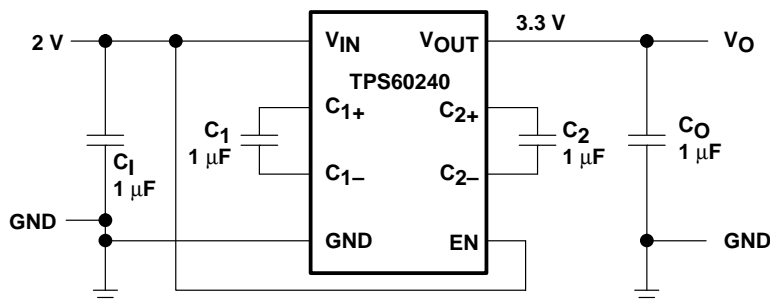


Figure 32. 2-V to 3.3-V Low-Noise Converter

output voltage ripple

The output voltage ripple depends on the capacitors used. Table 1 illustrates the dependence between output voltage ripple and capacitor selection.

Table 1. Output Voltage Ripple and Capacitor Selection

C ₁	C _O	C ₁	C ₂	OUTPUT VOLTAGE RIPPLE [μVrms]
1 μF	1 μF	1 μF	1 μF	288
2.2 μF	2.2 μF	1 μF	1 μF	212
4.7 μF	4.7 μF	1 μF	1 μF	183
4.7 μF	1 μF	1 μF	1 μF	272
1 μF	4.7 μF	1 μF	1 μF	185

NOTE: V_I = 3.3 V, V_O = 5 V, R_L = 500 Ω, T_A = 25°C

APPLICATION INFORMATION

components

For the best output ripple performance, low-ESR ceramic capacitors are recommended (see Table 2).

Table 2. Recommended Capacitors

PART	MANUFACTURER	PART NUMBER	VALUE	TOLERANCE	DIELECTRIC MATERIAL	PACKAGE	RATED VOLTAGE
C _I	Taiyo Yuden	LMK212BJ105KG-T	1 μF	10%	X7R	0805	10
	TDK	C2012X5R0J475K	4.7 μF	10%	X5R	0805	6.3
C _O	Taiyo Yuden	LMK212BJ105KG-T	1 μF	10%	X7R	0805	10
	TDK	C2012X5R0J475K	4.7 μF	10%	X5R	0805	6.3
C ₁ , C ₂	Taiyo Yuden	LMK212BJ105KG-T	1 μF	10%	X7R	0805	10
C _F	Taiyo Yuden	LMK212BJ105KG-T	1 μF	10%	X7R	0805	10

layout consideration

In order to get optimal noise behavior, keep the power lines to the capacitors and load as short as possible. Use of power planes is recommended.

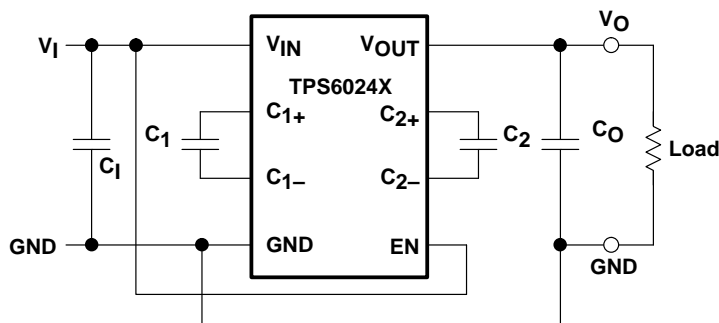


Figure 33. Layout Diagram

APPLICATION INFORMATION

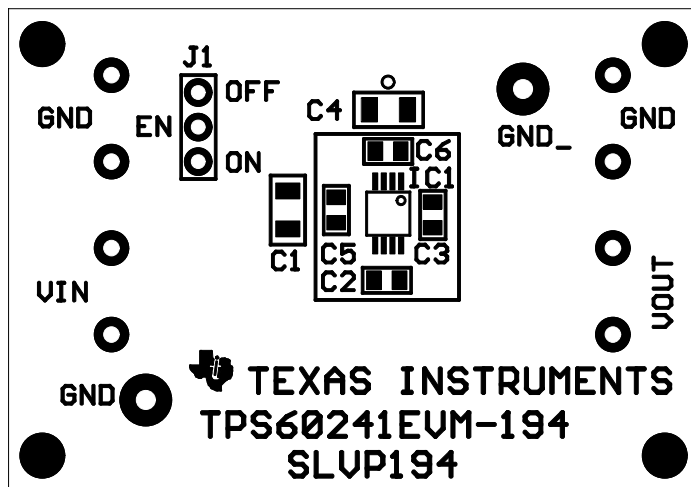


Figure 34. Top Silkscreen

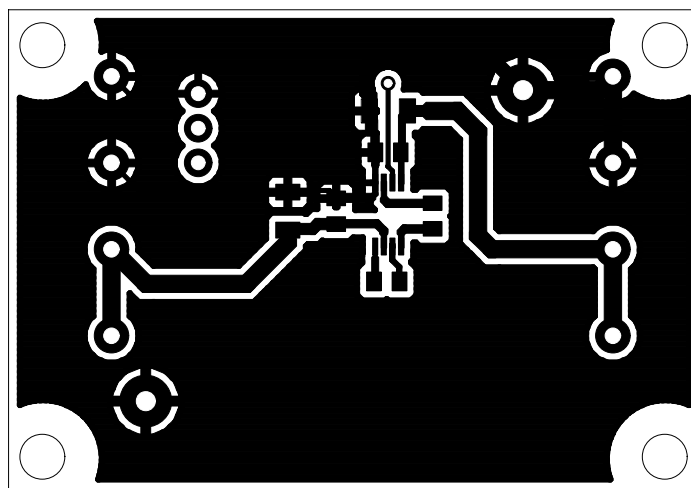


Figure 35. Top Layer

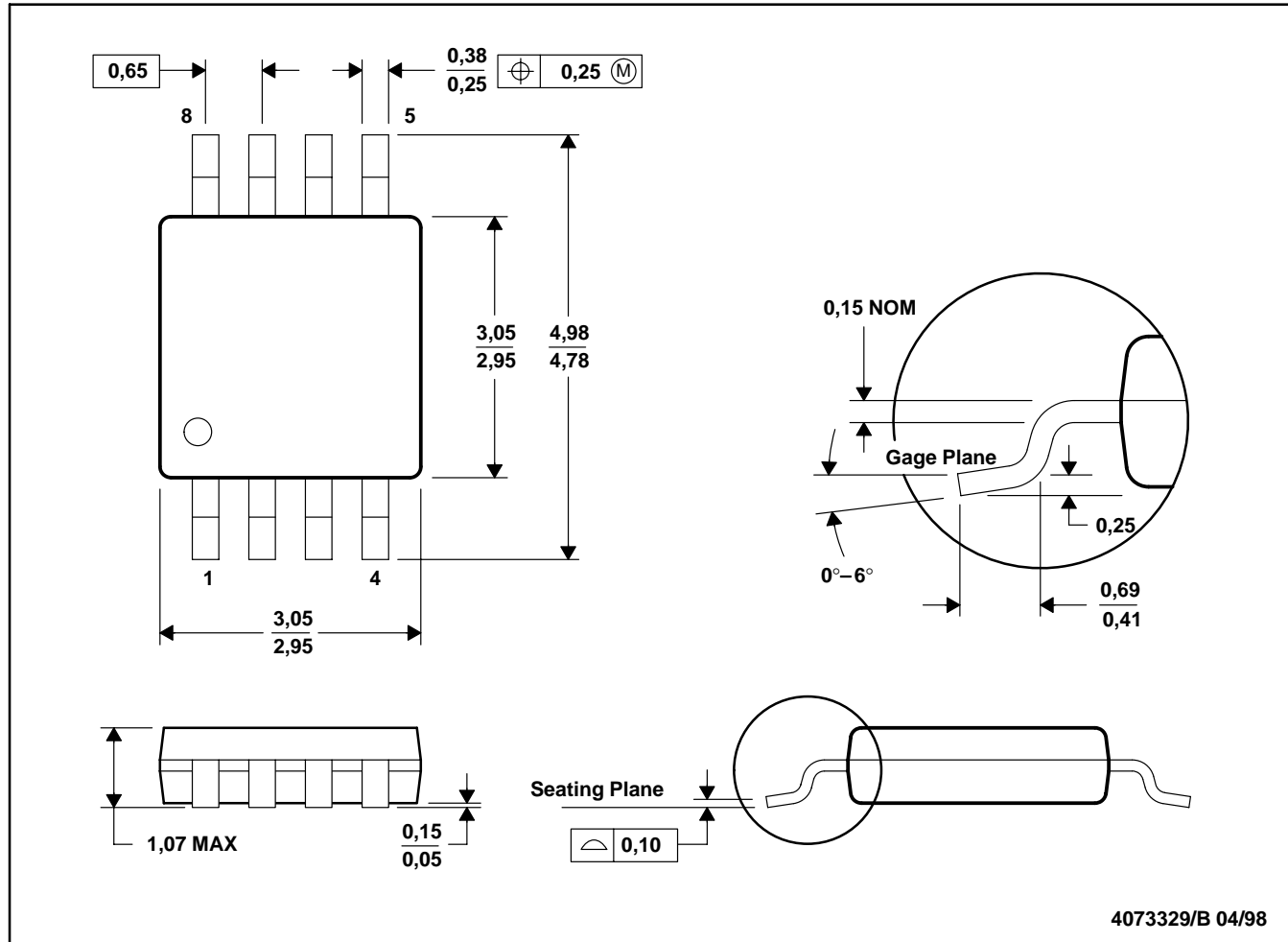
device family products

PART NUMBER	DESCRIPTION
REG710	30-mA switched cap dc/dc converter
REG711	50-mA switched cap dc/dc converter
TPS60110	Regulated 5-V, 300-mA low-noise charge pump dc/dc converter
TPS60111	Regulated 5-V, 150-mA low-noise charge pump dc/dc converter

MECHANICAL DATA

DGK (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion.
 D. Falls within JEDEC MO-187

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